



## **ES1A THRU ES1M**

SURFACE MOUNTED SUPER FAST RECTIFIER

VOLTAGE: 50 TO 1000V CURRENT: 1.0A

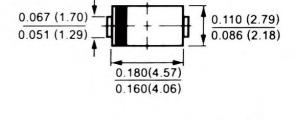
### SMA/DO-214AC

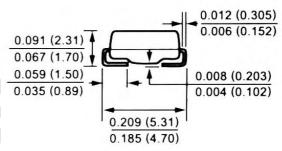
## **Features**

- Glass passivated junction chip
- ◆ For surface mounted application
- ◆ Low profile package
- ♦ Built-in strain relief
- High surge capability
- ◆ High temperature soldering guaranteed
  250°C/10sec/at terminal/complete device
- Superfast recovery time for high efficiency

### Mechanical data

- Cases: Molded with UL-94 class V-0 recognized Flame Retardant Epoxy
- Terminals: Plated axial leads solderable MIL-STD 202E, method 208C
- ◆ Polarity: Color band denote cathode end
- ♦ Weight:0.002 ounce, 0.064 gram





# Maximum ratings and electrical characteristics

Dimensions in inches and (millimeters)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Parameter	Symbols	ES1A	ES1B	ES1D	ES1G	ES1J	ES1K	ES1M	Units
Maximum recurrent peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	550	700	V
Maximum DC blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 3/8" lead length at $T_L$ =100 $^{\circ}$ C	I <sub>F(AV)</sub>	1.0							Α
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30.0							Α
Maximum instantaneous forward voltage at rated forward current	V <sub>F</sub>	0.95 1.3 1.7					.7	V	
Maximum DC reverse current Ta=25°C			10.0						μΑ
At rated DC blocking voltage Ta=125℃	I <sub>R</sub> 100.00							μΑ	
Maximum Reverse Recovery Time	Trr	35							nS
Typical junction capacitance	Сл	20.0							pF
Typical thermal resistance	$R_{JA}$	60.0							°C/W
Storage and operating junction temperature	T <sub>STG</sub>	-50 to +150							$^{\circ}$

Notes: 1. Measured at 1.0MHz and applied voltage of 4.0Vdc

- 2. Thermal resistance from junction to terminal mounted on 5×5mm copper pad area
- 3. Reverse recovery condition If=1.0A,Irr=0.25A